Unijunction Transistor

RoHS Compliant

Description:

A PN unijunction transistor in a TO–92 type package designed for use in pulse and timing circuits, sensing circuits and thyristor trigger circuits

Absolute maximum Ratings :

(Ta = +25°C unless otherwise specified)

Power Dissipation, P_D	: 300mW
Derate Above 25°C	: 3.0mW/°C
RMS Emitter Current, $I_{E(RMS)}$	: 50mA
Peak Pulse Emitter Current (Note 1) Current, i_E	: 1.5A
Emitter Reverse Voltage, V_{B2E}	: 30V
Interbase Voltage, V_{B2B1}	: 35V
Operating Junction Temperature Range, T_J	: -65°C to +125°C
Storage Temperature Range, Tstg	: -65°C to +150°C

Electrical Characteristics: (T_A = +25°C Unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Instrinsic Standoff Ratio		V_{B2B1} = 10V, Note3	0.56	-	0.75	-
Interbase Resistance	r_{BB}		4	6	9.1	kΩ
Interbase Resistance Temperature Coefficient			0.1	-	0.9	%/°C
Emitter Saturation Voltage	$V_{EB1(sat)}$	V_{B2B1} = 10V, I_E = 50mA, Note 4	-	2.5	-	V
Modulated interbase Current	$I_{B2(mod)}$	V_{B2B1} = 10V, I_E = 50mA	-	15	-	mA
Emitter Reverse Current	I_{EB20}	V_{B2E} = 30V, I_{B1} = 0	-	0.005	1	µA
Peak Point Emitter Current	I_P	V_{B2B1} = 25V	-	1	5	µA
Valley Point Current	I_V	V_{B2B1} = 20V, R_{B2} = 100Ω, Note 4	2	5	-	mA
Base-One Peak Pulse Voltage	V_{OB1}		3	6	-	V

Notes:

1. Duty Cycle <= 1% PRR = 10PPS.
2. Based upon power dissipation at Ta = +25°C
3. Intrinsic standoff ratio is essentially constant with temperature and interbase voltage and is defined by the equation:

$$\frac{Vp - Vbb}{Vd}$$

Where: Vp = Peak Point Emitter Voltage; Vbb = interbase Voltage;
Vd = Junction Diode Drop (~0.5V).

5. Use Pulse techniques: Pulse width ~ 300µS, Duty Cycle <= 2% to avoid internal heating due to inter-base modulation which may result in erroneous readings

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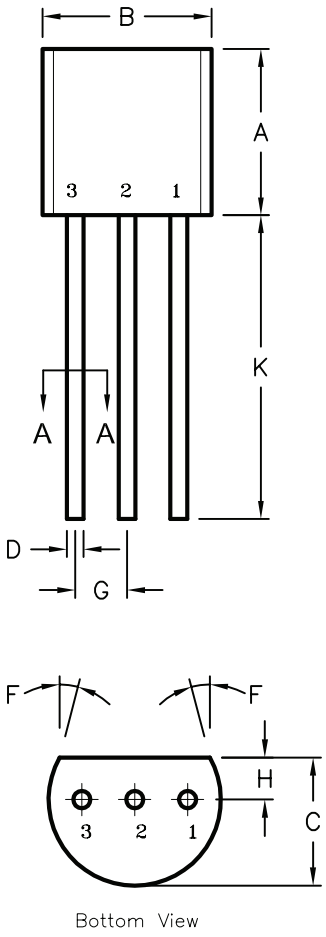
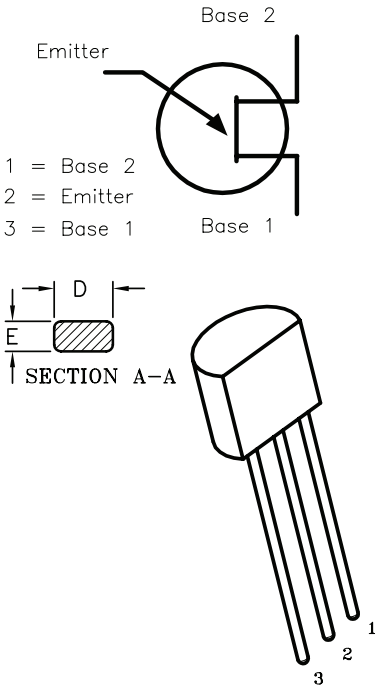
TO-92



Dim	Min	Max
A	4.3	5.33
B	4.45	5.2
C	3.18	4.19
D	0.41	0.55
E	0.35	0.5
F	5°	
G	1.14	1.4
H	1.14	1.53
K	12.7	-

Dimensions : Millimetres



Part Number Table

Description	Part Number
Unijunction Transistor, TO-92, PN	2N4870